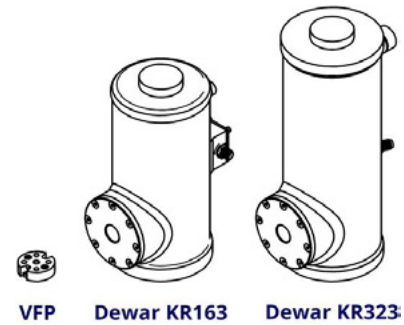




PC-LN2-14 DETECTOR SERIES

PRELIMINARY DATASHEET

**HgCdTe photoconductive
infrared detectors optimized
for operation at 77 K**



FEATURES

- Spectral range: over 17.0 μm
- Large active area
- Front-side illuminated
- Active element material optimized for operation at 77 K
- VFP is a specially designed flatpack package (without a window) optimized for easy self-assembly in LN2 metal dewars
- Possible assembly of a temperature sensor
- Active area dimension 0.25 mm $\times$ 0.25 mm available (on request)
- Other acceptance angle values available (on request)

APPLICATIONS

- FTIR spectroscopy

SERIES CONFIGURATION

Detector symbol	Cooling	Temperature sensor	Active area, A, mm×mm	Optical immersion	Package	Acceptance angle, Φ, deg.	Window
PC-LN2-14-1x1-VFP-NW-50	LN2 (for operation in 77 K)	no	1x1	no	VFP (flatpack)	~50	no
PC-LN2-14-1x1-VFP-KR163-wZnSeAR-50	LN2 T _{chip} ≐77K				VFP-KR163		wZnSeAR (3 deg. wedged zinc selenide, anti-reflection coating)
PC-LN2-14-1x1-VFP-KR323-wZnSeAR-50					VFP-KR323		

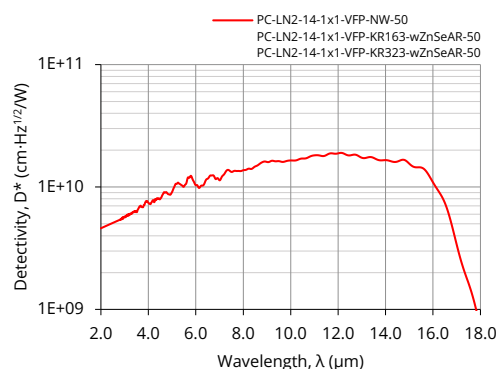
SPECIFICATION ($T_{\text{amb}} = 293\text{ K}$, $T_{\text{chip}} = 77\text{ K}$, $I_b = 15\text{ mA}$)

Detector symbol	Peak wavelength	Cut-off wavelength (10%)	Detectivity	Voltage responsivity	Resistance	Bias current
	λ_{peak}	$\lambda_{\text{cut-off}}$	$D^*(\lambda_{\text{peak}}, 20\text{kHz})$	$R_v(\lambda_{\text{peak}})$	R	I_b
	μm Typ.	μm Typ.	cm-Hz ^{1/2} /W Typ.	V/W Typ.	Ω Typ.	mA Typ.
PC-LN2-14-1x1-VFP-NW-50	12.1	17.4	1.9×10^{10}	500	50	15
PC-LN2-14-1x1-VFP-KR163-wZnSeAR-50						
PC-LN2-14-1x1-VFP-KR323-wZnSeAR-50						

VIGO Photonics S.A. reserves the right to change these specifications at any time without notification.

V3.0 13.01.2026

PC-LN2-14 DETECTOR SERIES PRELIMINARY DATASHEET


SPECTRAL RESPONSE (Typ., $T_{amb} = 293\text{ K}$, $T_{chip} = 77\text{ K}$, $I_b = 15\text{ mA}$)

MECHANICAL LAYOUT ON REQUEST
ABSOLUTE MAXIMUM RATINGS

Parameter	Test conditions, remarks	Value	Unit
Ambient operating temperature, T_{amb}	Operation at $T_{amb} > 30^\circ\text{C}$ may increase the liquid nitrogen consumption in the dewar	-20 to 30	$^\circ\text{C}$
Storage temperature, T_{stg}		-20 to 50	$^\circ\text{C}$
Storage humidity	No dew condensation	10 to 90	%
Maximum incident optical power density	Continuous wave (CW) or single pulses $> 1\text{ }\mu\text{s}$ duration	100	W/cm^2
	Single pulses $< 1\text{ }\mu\text{s}$ duration	1	MW/cm^2
Maximum bias current, $I_{b,max}$		25	mA

Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. Constant or repeated exposure to absolute maximum rating conditions may affect the quality and reliability of the device.

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